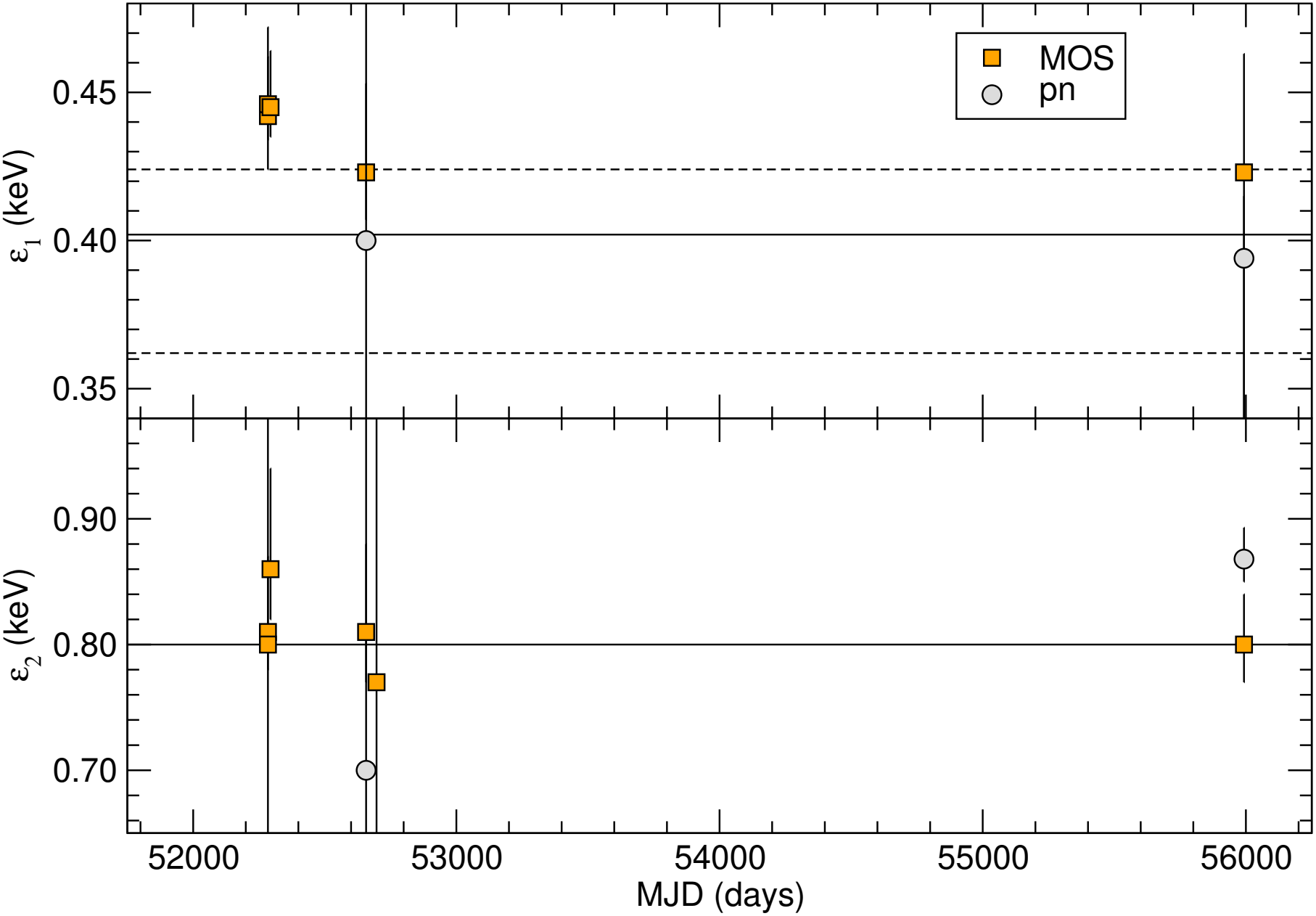
MOS
pn
0.45
0.40
0.35
ε_1 (keV)
0.90
0.80
0.70
ε_2 (keV)
52000
53000
54000
55000
56000
MJD (days)